JUL 1 6 2003

Docket No.: 50432-204 A PATENT

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Minh Van NGO, et al.

Serial No.: 09/986,267

Group Art Unit: 2812

Filed: November 08, 2001

Examiner: J. Brophy

For:

METHOD OF FORMING RELIABLE CU INTERCONNECTS

## **DECLARATION UNDER 37 CFR §1.131**

Honorable Commissioner of Patents and Trademarks Washington, DC 20231

Sir:

We, Minh Van Ngo, Arvind Halliyal and Eric Paton, hereby declare that::

- 1. We are the inventors of the invention disclosed and claimed in the abovereferenced United States patent application.
- 2. We are aware of the prosecution history of this application which was filed in the U.S. Patent and Trademark Office on November 8, 2001. We are also aware that the application is under rejection on various grounds, including a rejection under 35 U.S.C. §103 for obviousness predicated upon U.S. Patent 6,261,963 issued to Zhao et al. on July 17, 2001 based upon an application filed in the United States Patent and Trademark Office on July 7, 2000.

- 3. To our knowledge and in view of the factual evidence supplied herewith, the present invention was conceived in the United States prior to July 17, 2001, the issue date of the Zhao et al. patent. This fact is evidenced by the attached invention disclosure submitted to Advanced Micro Devices, Inc. (AMD), the assignee herein (Exhibit A hereto). Due diligence was exercised from prior to the issue date of July 17, 2001 to the filing date of the present application on November 8, 2001.
- 4. We further declare that all statements made herein of our own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful statement may jeopardize the validity of the application or any patent issuing thereon.

2/4/03	hinds ou his
Date	Minh Van Ngo
$\frac{21703}{\text{Date}}$	Arvind Halliyal
2/4/03	252
Date	Eric Paton

AMD INVENTION DISCLOSURE  TLD ID# 50267 Rec'd date  Sunnyvale x42110. return to MS68. Texas x55964 return to MS562	<b></b> )
Project:, Product:, Process:, Technology, to which the invention applies (identify):	
List 2 to 5 key words useful to search by to find patents or art related to this invention:	_
Working title of invention: To Climinate Voidings in a intle connects	_
INVENTOR/SESSION PARTICIPANT ADDRESS INFORMATION IS ON THE NEXT PAGE (1A)	
Inventor's signature:date:	
Inventor's printed full name: /W/H VAN NGO Citizenship:	
Employee #: Extension: Mail stop: Home telephone:( )	
Division: Directorate: Dept #: Dept : Manager:	-
Residence address:	
Post Office address:	
Co-Inventor's signature	
Co-Inventor's signature: date: date: Co-Inventor's printed full name: Hullingal Citizenship:	_
Employee #: Extension: Mail stop: Home telephone:( )	
Division: Directorate: Dept #: Dept : Manager:	
Residence address:	•
Post Office address:	
Co-Inventor's signature: date : Co-Inventor's printed full name: Citizenship:	
Co-Inventor's printed full name: Frice Pator Citizenship:	_
Employee #: Extension: Mail stop: Home telephone:( )	
Division: Directorate: Dept #: Dept : Manager:	
Residence address:	
Post Office address:	_
Co-Inventor's signature : date :	
Co-Inventor's printed full name: Citizenship:	-
Employee #: Extension: Mail stop: Home telephone:( )	_
Division: Dept #: Dept : Manager:	
Residence address:	•
Post Office address:	
	_
List on additional sheet if there are more co-inventors and list total number of inventors here:	
Name(s) of attorney(s) preferred by inventor(s) to prepare patent application, if known:	
LAW FIRM: MCDERMOTT, WILL & EMERY	
ATTORNEY: Arthur J. Steiner	
Witness 1 initial: Witness 2 initial:	
IDF CVR SHEET-grp 1-devices DB 7/31/1995 printed 59901 8:53 PM. page rev 11/25/1996  AMDI CONFIDENTIAL Page 1	

ID INVENTION DISCLOSUR California x42110, return to MS68, Texas x55964 r	
	T 10 To (0)
e the problem solved by this invention:	Language gette grant between to (BMI)
1 1 55	
and the MAN	I to eliminate la voiding in interce
	O
f description and/or sketch of invention (p	olease attach copies of AMD patent notebook pages, reports or
vings):	The state of the s
- 1	V ( 7 . 18 \ )
, Taw/	Ta (BMD)
Les Velaos	We have seen many voidings in
P 160's	interconnects dirring the phrocessing
	- H. D. C. T. J. F. J. F.
322 - 31N	of HiP6 L & HiP7 at both
FTecs	7
	Amp Fabs. These voidings are
·	/ []
lings/	major concerns for the circuit
CIE	La
	retability ( low EM).
	N Y I I C P \
11Se LTA /: NAz	anneal at high temp to flow-in
(, voidings, Seal	-off voiding at post in platting
	10 8 1 1 g
before in CMP	• • • • • • • • • • • • • • • • • • • •
	NIT flow raig = - to - SCM
	10 c) 10 10 C
	Coser Mener: - te -
nt notebook # Page numbers	Number of drawings
•	
ness 1 initial: Witnes	ss 2 initial:
iess i uuliai. Wilhes	55 & HULIAI